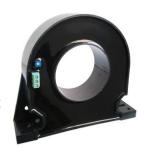


## CSM2000LTE Hall-effect Current Sensor Series

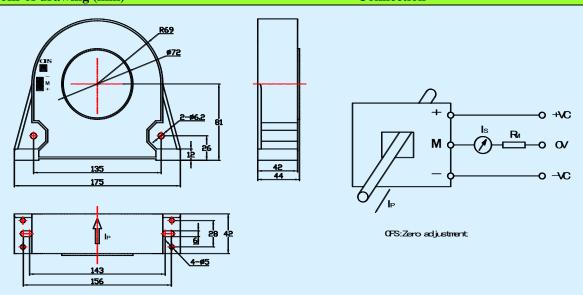


Closed loop current sensor based on the principle of Hall-effect. It can be used for measuring AC,DC,pulsed and mixed current.

Electrical characteristics			
	Туре	CSM2000LTE	
$I_{PN}$	Primary nominal input current(rms)	2000	A
$I_P$	Measuring range of primary current(DC)	0∼±3000	A
$I_{SN}$	Secondary nominal output current	400±0.25%	mA
$\mathbf{K}_{\mathbf{N}}$	Conversion ratio	1:5000	
$\mathbf{R}_{\mathbf{M}}$	Measuring resistance (V <sub>C</sub> =±15V)	$V_C = \pm 15V$ $I_P = \pm 2000$ 0~8	Ω
	$(V_C=\pm 15V)$	$V_C = \pm 15V$ $I_P = \pm 2200$ 0~5	Ω
	$(V_C = \pm 18V)$	$V_C = \pm 24V$ $I_P = \pm 2000$ 5~29	Ω
	$(V_C = \pm 18V)$	$V_C = \pm 24V$ $I_P = \pm 3000$ 5~11	Ω
$\mathbf{v}_{\mathbf{c}}$	Supply voltage	±15~±24(±5%)	V
$I_{C}$	Current consumption	$V_C = \pm 24V$ 28+Is	mA
$V_D$	Insulation voltage	AC/50Hz/1min 6	kV
$\epsilon_{ m L}$	Linearity	<0.1	%FS
X	Accuracy	$T_A=25$ °C <±0.7	%
$I_0$	Zero offset current	$T_A=25^{\circ}C$ <±0.25	mA
I <sub>OT</sub>	Thermal drift of I <sub>0</sub>	$I_{P}=0$ $T_{A}=-25\sim+85^{\circ}C$ $<\pm0.005$	mA/℃
$T_r$	Response time	90%I <sub>PN</sub> <1	μs
di/dt	di/dt accurately followed	>100	A/μs
f	Frequency bandwidth(-1dB)	DC~100	kHz
$T_A$	Ambient operating temperature	-25~+85	င
$T_{S}$	Ambient storage temperature	-40~+100	င
$\mathbf{R}_{\mathbf{S}}$	Secondary coil resistance(T <sub>A</sub> =25°C)	25	Ω
	Standard	Q/320115QHKJ01-2010	

## **Dimensions of drawing (mm)**

## Connection



## Remarks

Incorrect connection may lead to the damage of the sensor.  $I_{SN}$  is positive when the  $I_P$  flows in the direction of the arrow.

Dynamic performance (di/dt and response time) are best with a primary bar in the center of the through-hole.